

Datasheet V2019.1.0

G3S065100P

650V/ 100A Silicon Carbide Power Schottky Barrier Diode

Features

- Rated to 650V at 100 Amps
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behaviour
- High temperature operation
- High frequency operation

Key Characteristics			
V _{RRM}	650	V	
IF	-	Α	
Q _c	385	nC	

Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

Part No.	Package Type	Marking
G3S065100P	TO-247AC	G3S065100P



Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse	V _{RRM}		650	V
Voltage				v
Surge Peak Reverse	V _{RSM}		650	
Voltage				
DC Blocking Voltage	V _{DC}		650	
Continuous Forward	1	-	-	۸
Current	I _F			A
Repetitive Peak Forward	1	$T_C=25^{\circ}C$, tp=10ms, Half Sine	_	А
Surge Current	I _{FRM}	Wave, D=0.3		
Non-repetitive Peak		$T_C=25^{\circ}C$, tp=10ms, Half Sine	-	А
Forward Surge Current	I _{FSM}	Wave		
	P _{TOT}	T _C =25°C	484	W
Power Dissipation		T _C =110°C	210	W
Operating Junction	T _i		-55°C to 175°C	°C
	,		-55°C to 175°C	
Storage Temperature	T_{stg}		55 0 10 175 0	°C
		M3 Screw	1	Nm
Mounting Torque		6-32 Screw	8.8	lbf-in

Thermal Characteristics

Parameter	Symbol	Test Condition	Value	Linit
	Symbol	lest condition	Тур.	Unit
Thermal resistance from junction to case	R_{thJC}		0.31	°C/w

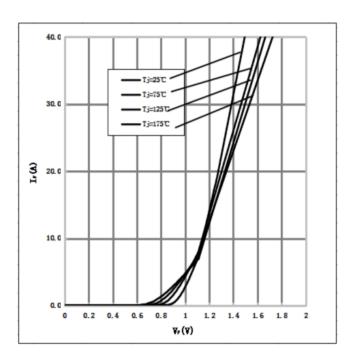
Deremeter	Symbol	Test Conditions	Numerical		11
Parameter	Symbol	Test conditions	Тур.	Max.	Unit
	VF	I _F =40A, Tj=25℃	1.4	1.7	V
Forward Voltage		I _F =40A, Tj=175℃	1.7	2	V
Deverse Current	I _R	V _R =650V, T _j =25℃	10	50	A
Reverse Current		V _R =650V, T _j =175℃	20	100	μΑ
		V _R =400V, T _j =150°C			
Total Capacitive Charge	Q _C	$Qc = \int_0^{VR} C(V)dV$	385	-	nC
		V _R =0V, T _j =25 ℃, f=1MHZ	13500	14000	
Total Capacitance	C	V _R =200V, T _j =25℃, f=1MHZ	745	755	рF
		V _R =400V, T _j =25 °C , f=1MHZ	730	740	

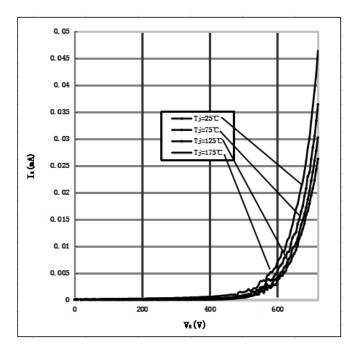
Electrical Characteristics

Performance Graphs

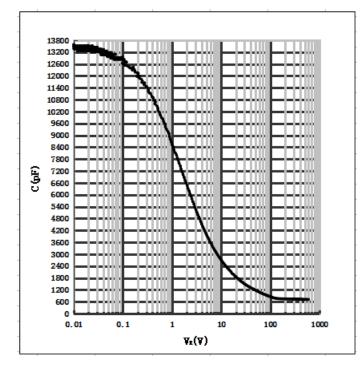
1) Forward IV characteristics as a function of Tj :



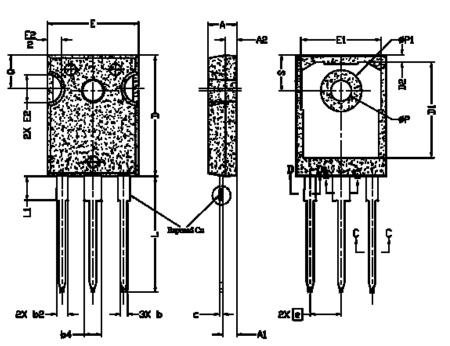




3) Capacitance vs. reverse voltage :



Package TO-247



CUMDOL	DIMENSIONS			
SYMBOL	MIN	NOM	MAX	NOTES [
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
b4	2.87	3.00	3.22	6,8
b5	2.87	3.00	3.18	
с	0.55	0.60	0.69	6
c1	0.55	6.00	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
е		5.44 BSC		
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ΦP	3.56	3.61	3.65	7
ΦP1		7.19 REF		
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: <u>http://globalpowertech.cn/English/index.asp</u>

More product datasheets and company information can be found in: <u>http://globalpowertech.cn/English/index.asp</u>

